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|--|---------------------------------------|--|--------------|
| <b>Module code</b>   | SP-2206                               |  |              |
| <b>Module Title</b>  | Condensed Matter Physics              |  |              |
| <b>Degree/Diploma</b>  | Bachelor of Science (Applied Physics) |  |              |
| <b>Type of Module</b>  | Major Option                          |  |              |
| <b>Modular Credits</b>   | 4                                     | <b>Total student Workload</b>  | 8 hours/week |
|  |                                       | <b>Contact hours</b>   | 4 hours/week |
| <b>Prerequisite</b>  | None                                  |  |              |
| <b>Anti-requisite</b>  | SP-2306 Condensed Matter Physics      |  |              |
| <b>Aims</b>  |                                       |  |              |
| To provide fundamental studies of the properties of crystalline and non- crystalline materials at the microscopic level and to relate these studies to the applications of materials in microelectronic, optoelectronic, and other industries.   |                                       |  |              |
| <b>Learning Outcomes</b>   |                                       |  |              |
| <i>On successful completion of this module, a student will be expected to be able to:</i>  |                                       |  |              |
| Lower order :  | 30%                                   | <ul style="list-style-type: none"> <li>- Identify crystal structures of solids, and explain electronic band structures.</li> <li>- Understand the theory on free electron model and models of heat capacity in solids.</li> </ul>                              |              |
| Middle order :   | 60%                                   | <ul style="list-style-type: none"> <li>- Analyse X-ray diffraction patterns</li> <li>- Analyse the electron energy distribution in solids using the Fermi – Dirac function</li> <li>- Apply the principles of semiconductors to solid state devices</li> </ul> |              |
| Higher order:  | 10%                                   | <ul style="list-style-type: none"> <li>- Evaluate the outcome of the analyses</li> <li>- Work in a group to relate theory with application, and communicate individually in the form of presentation or report.</li> </ul>                                     |              |
| <b>Module Contents</b>   |                                       |  |              |
| <ul style="list-style-type: none"> <li>- Crystal structures, bonding in solids, crystal diffraction</li> <li>- Crystal dynamics, lattice heat capacity, concept of phonon, thermal conduction</li> <li>- Free electron model, quantum theory of metals, Fermi distribution, electron transport</li> <li>- Electron band structure, semiconductors, origin of band gap</li> <li>- Solid state devices, p-n junction, transistors, diode, solar cells, etc.</li> </ul> |                                       |  |              |
| <b>Assessment</b>  | Formative assessment                  | Weekly Tutorial Sessions and Discussion  |              |
|  | Summative assessment                  | Examination: 60%   |              |
|  |                                       | Coursework: 40% <ul style="list-style-type: none"> <li>- 2 Individual Written Assignments (20%)</li> <li>- 1 Class Test (10%)</li> <li>- 1 Group Presentation (10%)</li> </ul>   |              |